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High gain - high power (HGHP) DC-DC converter for DC microgrid applications: Design and testing

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Abstract

The use of green energy sources to feed DC microgrids is gaining prominence over traditional centralised AC systems. DC microgrids are characterised by the use of intermediate DC-DC converter which acts as power conditioning units. Hence, the choice of an appropriate DC-DC converter becomes significant as the overall system efficiency is strongly dependent on the converter’s performance. This paper proposes a novel high gain high power (HGHP) DC-DC converter for DC microgrid, which is of one of the significant step forward in the development of DC microgrids. The suitability of the proposed HGHP DC-DC converter is demonstrated by experimental tests of the 60V/1.1kV, 3kW converter; test results validate the converter’s suitability for DC distribution. A significant number of performance parameters of the proposed converter is compared with state of the art converter topologies demonstrating the superior capabilities of the proposed converter. This paper also portrays the potential benefits that could be reaped by trending towards DC instead of existing AC system. The advantages and challenges to be confronted in the foreseeable future while implementing sustainable DC microgrids are also highlighted. Finally, this paper encapsulates renewable energy fed DC microgrid system as an
appropriate, technically feasible, economically viable and competent solution for efficiently utilising the sustainable energy sources.

**Keywords:** Power electronics applications; Microgrid; DC-DC converter; Renewable energy integration; Distributed generation; High gain; Power conversion

1 **Introduction**

Electrical energy generated from fossil fuel sources is an option to fulfil the ever increasing load requirement. However, the process of electrical energy conversion from conventional energy sources (e.g. oil) pollutes the atmosphere leading to drastic and undesirable climatic fluctuations. The twin challenges of meeting the present day electrical energy demand while causing least damages to the environment are both massive and contradictory. Distributed renewable sources (DRSs) lend a great helping hand to confront this situation [1], [2]. Hence, among energy conscious planners, there is a significant inclination to efficiently convert and utilise electrical energy from the never exhausting, secure and non-polluting energy resources like solar, wind, etc [3],[4],[5]. Such a distributed renewable energy system should be simple, efficient, independent and stiff enough to replace the existing conventional system [6]. Moreover, the distributed renewable energy sources (RES) should possess desirable attributes: [7]

(i) Electricity energy storage facility [8];

(ii) Appropriate protection, monitoring and control mechanism;

(iii) Ability to operate in islanded and grid connected mode to ensure reliability;

(iv) Compatible with similar and other RES [9], [10] and

(v) Smart enough to prioritise the load demand based on supply availability [11].
The concept of a microgrid (μ-grid) is emerging as an excellent solution for interconnecting RES and the loads. [12]. The main advantage of microgrids, from the reliability point of view, is that they can operate in both islanded as well as grid connected mode [13], [14]. Residential, commercial, and/or industrial loads are connected to a microgrid. [15]. The overall performance of a microgrid system depends on the type of distribution used to supply the loads [16], [17]. As present day loads operate from AC supply, AC distribution continues to be in vogue for more than a century. Fig. 1 shows a general schematic representation of a typical conventional AC power system systems, the uni-directional power flow from generation to load is depicted.

![Fig. 1. Schematic diagram representing the main components of a traditional AC system.](image)

The use of DC system on microgrid application is a realistic option. The DC distribution systems have good techno-economical potential compared to existing AC systems [18]. The use of low voltage DC (LVDC) has proven to be beneficial for the distribution networks [19]. LVDC is ideally suited for distribution networks due to its efficiency for shorter transmission distances and smaller transmission powers [20]. Also, DC distribution systems, particularly DC microgrids, make the grid more controllable, stable and reliable [21]. In DC distribution system, as capacitive leakage and inductive impedances do not exist in steady-state, higher power can be transferred with lesser voltage variation levels [22]. Further, like frequency, phase and reactive power requirements need not be considered in a DC microgrid, integrating many such DC microgrids to form a macro grid is simple. Therefore, planning, implementation and operation are simpler and less expensive [23].

Moreover, DC microgrids are more efficient than AC systems because:
(i) Certain energy-intensive manufacturing operations like smelting of aluminium, paper and pulp production units which waste more than 6% of total energy consumed in AC to DC conversion [24];

(ii) Data centres which operate at 10% higher efficiency, 20% less installation cost and 10% reduced equipment cost [25];

(iii) DC electrical loads such as LED lighting and electronic gadgets which are 20% of total electricity consumers in residential and commercial buildings [26];

(iv) Charging stations for electric vehicles, heating, ventilation and air-conditioning (HVAC) systems and various household appliances are well suited to DC power [27].

Fig. 2(a) shows the schematic diagram showing the general structure of a DC microgrid operating and the possibility of operating in grid-connected and off-grid mode. Various types of loads (critical and non-critical) connected to the DC microgrid are also clearly represented. Fig. 2(b) shows the schematic of a standalone DC microgrid feeding native DC loads and industrial variable frequency drives (VFD).
Fig. 2. Schematic diagram of a DC microgrid.

(a) Operating in grid-connected and off-grid mode.

(b) Operating in standalone mode.

Though it is extremely difficult and expensive to replace the present AC distribution system by DC, bypassing the existing AC grid and forming smaller DC microgrids is a viable alternative. The evolution could be like a DC layer overlapping the pre-existing AC layer. The evolution can be achieved by integrating RES with loads while avoiding unnecessary rectification and inversion stages are technically feasible as well as economically viable [28]. DC microgrids commendably integrate distributed generation sources, energy storage devices and a large variety of loads compared to AC microgrids.

Regarding social aspects, renewable energy fed DC microgrid is an affordable, more efficient, much faster and easier solution to demand and supply especially in rural areas [29]-[31].

In a DC microgrid, the crucial part of a DC distribution system is the DC-DC converter. To establish a competent renewable fed DC distribution system, proper selection and design of DC-DC converter with high voltage step up and high power handling capability is essential [32]. Other important features that motivate selection of a converter for DC distribution are discussed in [16] and [33].
For a RES fed DC distribution systems, a DC-DC converter capable of offering higher voltage step-up ratio is essential. Power distribution (in the range 2kW to 5kW) at 50V DC voltage level is inefficient due to higher cable loss. The higher voltage rating of the order of 1kV in the DC distribution system leads to smaller currents power losses compared to low voltage AC system [34]-[38].

According to EU low voltage directive (LVD 72/23/EEC), the use of 1 kV DC as a third distribution voltage level has proved to be a cost-efficient and effective solution to enhance the reliability of electricity distribution.

Conventional boost and boost derived converters are not suitable for high voltage gain applications as they suffer from practical issues like extreme duty ratio operation, large voltage stress on the switch, diode reverse recovery problems and poor efficiency [39]-[41]. Interleaved boost converters (IBC) are preferred for higher power ratings because of their inherent current sharing [42]-[44]. Non-isolated converters with appropriate gain extension techniques are preferred over isolated converters (which use transformers) mainly due to their merits like higher efficiency, reduced volume and size. Some of the commonly used gain extension methods are coupled inductor (CI) with and without IBC [45], [46], switched capacitor cells, voltage doublers [47], voltage multiplier cells (VMCs) [48] and charge pump technique. Though modular multilevel converters can cater to the high gain requirements, higher component count reduces their efficiency.

Active and passive voltage clamping are also employed in few converters to suppress the voltage stress on the power switches [49]. Some CI based topologies like winding cross-coupled inductors (WCCI), dual coupled inductor [50], switched coupled inductor, multi-winding [51] and multi CI based converters [52]-[54] are not very popular due to manufacturing complexity and larger switch voltage stress.
Switched-capacitor (SC) based converters alleviate the necessity of magnetic components resulting in compact and light power converters [55]. Unfortunately, the achievable voltage gain is only integral times the number of SC cells used. In [56], the high step-up conversion ratio is achieved by combining CI and SC. Voltage balancing of output capacitors which are located between adjacent SC cells is another tricky issue.

DC-DC converter topologies available in the literature are capable of offering either high voltage gain (>15) or handle large power levels (>1kW). Moreover, the existing DC-DC converters do not inherit many or few of the above-mentioned features which are vital for DC microgrids. Therefore, a most appropriate novel high gain high power DC-DC converter fulfilling most of the requirements of a DG fed DC microgrids is presented in this paper.

This paper proposes an extended version of a high gain high power (HGHP) converter which is presented in [57]. The proposed HGHP converter is one of the significant steps forward in the development of DC microgrids. The paper is organised as follows: Section 1 introduces the conceptual background and state of the art of high gain converters available in the literature, Section 2 describes the proposed HGHP topology, its operating principle and design details. Section 3 discusses the hardware tests and the results obtained. Section 4 presents the details regarding the converter performance which are compared with few existing converters. Sections 5 and 6 discuss the challenges and prospects of the proposed HGHP converter when employed in DC microgrids. Section 7 provides the concluding remarks.
2 Proposed HGHP DC-DC Converter

2.1 Topology Description and Operating Principle

Fig. 3(a) shows the power circuit diagram of the proposed converter. The converter structure comprises of two stages. Stage 1 is formed by a three phase IBC with the primary winding of three CIs, a voltage lift capacitor ($C_{lift}$) and a voltage lift diode ($D_{lift}$). The three legs of the IBC are operated with a uniform phase shift of 120° between them to reduce the input current ripple. $C_{lift}$ and $D_{lift}$ are used to multiply the voltage gain of the IBC by the number of interleaved phases. In Stage 2, each secondary winding of the CI acts as a voltage source to the VMCs formed by multiplier diodes ($D_{M1}$-$D_{M6}$) and multiplier capacitors ($C_{M1}$-$C_{M6}$). Three such arrangements are connected in series to extend the voltage gain. The rearranged version of Stage 2 is shown as an inset for clarity. Stage 1 and Stage 2 are cascaded through a diode ($D_{IBC}$) to prevent feedback of stored energy from the CIs. Diode $D_0$ acts as the classical boost rectifier diode while output capacitor $C_0$ is used to limit the output voltage ripple. This novel hybrid arrangement of CIs and VMCs enables this converter to yield higher voltage gain and handle higher power simultaneously. The operating modes are presented in [57]. Fig. 3(b) shows the characteristic waveforms of the proposed HGHP converter.
2.2 Steady State Analysis

This section is dedicated to analyse the proposed HGHP converter operating under the steady-state condition and derive key design details. Mathematical expressions describing important design parameters like (i) voltage conversion ratio, (ii) voltage and current stress across the semiconductor devices and (iii) passive elements are derived and presented.

2.2.1 Voltage Conversion Ratio

Stage 1 of the proposed converter is a three phase IBC. As voltage lift technique has been employed, the voltage gain of Stage 1 ($V_{\text{stage1}}$) is given by

$$V_{\text{Stage 1}} = V_{\text{IBC}} = V_{C_{\text{lift}}} = \frac{3}{1-D} V_{\text{in}}$$

(1)

where $V_{\text{IBC}}$ is the voltage across the IBC stage, $V_{\text{in}}$ represents the input voltage, $V_{C_{\text{lift}}}$ indicates the potential across $C_{\text{lift}}$ with respect to ground and $D$ represents the duty ratio of the switches.

Stage 2 of the proposed converter comprises of VMCs which are embedded with the secondary winding of each CI. Therefore, the voltage obtainable through Stage 2 ($V_{\text{stage2}}$) is

$$V_{\text{Stage 2}} = n\left(\frac{3k}{1-D}\right) V_{\text{in}}$$

(2)

where $n$ represents the turns ratio of CI and $k$ is the coefficient of coupling.

Using (1) and (2), the voltage gain ($M$) of the proposed converter is derived as

$$M = \frac{V_0}{V_{\text{in}}} = \frac{3(1+nk)}{1-D}$$

(3)

where $V_0$ is output voltage.
Generalising above shown approach, for a converter employing $P$ number of interleaved phases (with $P$ number of CIs each having $n$ turns ratio with $k$ being the coupling coefficient) and $P$ number of VMCs, the overall voltage gain $M_{\text{Generalized}}$ can be deduced as:

$$M_{\text{Generalized}} = \frac{V_0}{V_{\text{in}}} = \frac{P(1+nk)}{1-D}$$  \hspace{1cm} (4)

### 2.2.2 Switch Voltage Stress

Due to asymmetrical structure of Stage 1, voltage stress on the switches ($V_{Z_1}, V_{Z_2}, V_{Z_3}$) is different and expressed as

$$V_{Z_1} = V_{Z_2} = \frac{3}{1-D}V_{\text{in}} = \frac{V_0}{1+nk}$$  \hspace{1cm} (5)

Switch $Z_3$ experiences a voltage stress similar to the switch present in a classical boost converter (CBC). Therefore,

$$V_{Z_3} = \frac{1}{1-D}V_{\text{in}} = \frac{V_0}{3(1+nk)}$$  \hspace{1cm} (6)

Though the voltage stress on all the three power switches is unequal ($V_{Z_1} = V_{Z_2} \neq V_{Z_3}$), the converter performance is not affected. All the three switches ($Z_1$, $Z_2$ and $Z_3$) are chosen with identical voltage rating for ease of fabrication.

### 2.2.3 Diode Voltage Stress

The diode $D_1$ is OFF when $Z_3$ conducts whereas diode $D_{\text{lift}}$ is OFF when $Z_1$ is ON. Both $D_1$ and $D_{\text{lift}}$ must be rated to block the voltage obtained from one interleaved phase. Therefore,

$$V_{D_1} = V_{D_{\text{lift}}} = \frac{1}{1-D}V_{\text{in}}$$  \hspace{1cm} (7)
The voltage stress on $D_M$ ($V_{D_M}$) is obtained when $D_M$ conducts. By applying Kirchhoff's Voltage Law (KVL) around the loop involving $C_{lift}$, $D_{IBC}$, $D_M$ and $C_M$, the voltage stress is derived as

$$V_{D_M} = V_{C_M} - V_{C_{lift}}$$

(8)

$V_{C_M}$ represents the voltage across $C_M$ and $V_{C_{lift}}$ indicates the voltage across $C_{lift}$.

The voltage across $C_M$ is given by

$$V_{C_M} = V_{C_{lift}} + \left( \frac{nk}{1-D} \right) V_{in}$$

(9)

Substituting (9) in (8),

$$V_{D_M} = \left( \frac{nk}{1-D} \right) V_{in}$$

(10)

From VMC concept, voltage stress on other multiplier diodes $D_M - D_M$ is equal to (10). As $D_M$ is present closer to the output terminals, its voltage stress is minimum and same as the stress on $D_0$. Although voltage across adjacent multiplier cells increases steadily, the voltage stress on the multiplier diodes is equal. Therefore, diodes with identical voltage rating are used while fabricating.

### 2.2.4. Current Stress on Semiconductor Devices

Stage 1 of the proposed converter is asymmetrical due to the introduction of $C_{lift}$. The RMS value of currents flowing through $Z_1$, $Z_2$ and $Z_3$ are given by

$$I_{Z_1} = \frac{2}{3} I_{in}, I_{Z_2} = I_{Z_3} = \frac{1}{6} I_{in}$$

(11)

The RMS value of current stress on $D_1$ and $D_{lift}$ will be same as the current through $Z_3$ and $Z_1$ respectively. Thus,
\[ I_{D_1} = I_{Z_5} = \frac{1}{6} I_{in} \] (12)

\[ I_{D_{hih}} = I_{Z_1} = \frac{2}{3} I_{in} \] (13)

Since \( D_{IBC} \) and \( D_{M1} \) are present just after Stage 1, the current through them is

\[ I_{D_{ac}} = I_{D_{M1}} = \frac{1-D}{3} I_{in} \] (14)

Since the multiplier diodes \( D_{M2} - D_{M6} \) are present in the gain extension stage, the RMS current through these diodes progressively decrease and are expressed as

\[ I_{D_{a2}} = I_{D_{M3}} = \frac{1-D}{3+nk} I_{in} \] (15)

\[ I_{D_{a4}} = I_{D_{M5}} = \frac{1-D}{3+2nk} I_{in} \] (16)

\[ I_{D_{a6}} = \frac{1-D}{3+3nk} I_{in} \] (17)

The diodes \( D_{M6} \) and \( D_0 \) must be rated to carry the full load current \( I_0 \). Therefore,

\[ I_{D_{a6}} = I_{D_0} = I_0 \] (18)

### 2.2.5. Design of Passive Components

The proposed high gain high power (HGHP) DC-DC converter for DC microgrid is intended to be used in PV integration. The input current ripple of a DC-DC converter used in PV applications should be minimised to harness the maximum power from the input PV panels efficiently. While designing the inductor, a judicious trade-off is made between its size
and current ripple. For the CIs used in the proposed converter, the primary winding inductance \( L_{\text{Primary}} \) is determined from

\[
L_{\text{Primary}} = \frac{V_{\text{in}}(V_{C_{\text{lift}}} - 3V_{\text{in}})}{3f\Delta i_{L}V_{C_{\text{lift}}}}
\]  

(19)

where \( f \) is the switching frequency and \( \Delta i_{L} \) represents the input current ripple.

The inductance value of the secondary winding is computed from the turns ratio \( n \). The turns ratio is decided based on the required voltage gain and is expressed as

\[
n = \frac{1}{k}\left[\frac{M(1-D)}{3} - 1\right]
\]  

(20)

The voltage across \( C_{M1}, C_{M3}, \) and \( C_{M5} \) is same as the voltage impressed across \( L_{3S}, L_{2S}, \) and \( L_{1S} \) respectively. Since the three CIs have same turns ratio and coupling coefficient, voltage across these capacitors are same and given by

\[
V_{C_{M1}} = V_{C_{M3}} = V_{C_{M5}} = \left(\frac{nk}{1-D}\right)V_{\text{in}}
\]  

(21)

The voltage across \( C_{M2} \) is given by (9). Each VMC cell contributes to a voltage gain given by (21). Therefore, voltage across \( C_{M4} \) and \( C_{M6} \) is deduced as

\[
V_{C_{M4}} = V_{C_{M2}} + \left(\frac{nk}{1-D}\right)V_{\text{in}}
\]  

(22)

\[
V_{C_{M6}} = V_{C_{M4}} + \left(\frac{nk}{1-D}\right)V_{\text{in}}
\]  

(23)

The output capacitor value \( C_{0} \) is determined from duty ratio \( D \), output current \( I_{0} \), output voltage ripple \( \Delta V_{0} \) and the switching frequency \( f \) as

\[
C_{0} = \frac{DI_{0}}{f\Delta V_{0}}
\]  

(24)
3 Hardware Tests and Results

The proposed HGHP DC-DC converter suitable for DC microgrid applications has been implemented and then tested in order to demonstrate the suitability and the performance of the proposed concept. The hardware implementation is based on the parameters and specifications shown in Table 1. The gate pulses to switches $Z_1$, $Z_2$ and $Z_3$ are generated using TMS320F28027 digital signal processor (DSP). SCALE driver board 2AP043512 is used to interface the control and power circuit. The driver board and power module are kept in close proximity to reduce EMI issues. Tektronix makes TPS2024B digital storage oscilloscope (DSO) with four isolated channels along with standard accessories like P5210 high voltage probe, and A622 current probes are used to capture the key experimental waveforms. Fig. 4 shows the photograph of the experimental setup described above.

Fig. 4. Photograph showing the experimental setup of the proposed converter.
The first experimental test is performed to verify the high gain high power handling capability of the proposed converter considering a 60V input and 3kW load. Fig. 5(a) shows the experimental waveforms of the gate pulses (CH1-CH3) and output voltage, \( V_0 \) (CH4). The experimental measurements demonstrate the duty ratio, frequency and the phase shift between each pulse are fulfill the system requirement and specification defined in Table 1. Also, the experimental waveform of the output voltage exhibits a very low ripple as predicted from the design and specifications. The experimental results of the voltage waveforms in used to demonstrate the conversion ratio (18.3) of the proposed converter, and it is clear the requirements are properly fulfilled, the waveforms are presented in Fig. 5(b) and they perfectly match the theoretical value defined in the design stage.

**Table 1. Specifications of the main components of the proposed HGHP DC-DC converter for DC microgrid.**

<table>
<thead>
<tr>
<th>Parameters</th>
<th>Specifications / Part Number</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input voltage, ( V_{in} )</td>
<td>60 V</td>
</tr>
<tr>
<td>Output voltage, ( V_0 )</td>
<td>1.10 kV</td>
</tr>
<tr>
<td>Output power, ( P_0 )</td>
<td>3 kW</td>
</tr>
<tr>
<td>Switching frequency, ( f )</td>
<td>100 kHz</td>
</tr>
<tr>
<td>Duty ratio, ( D )</td>
<td>0.55</td>
</tr>
<tr>
<td>Turns ratio, ( n )</td>
<td>2.0</td>
</tr>
<tr>
<td>Coefficient of coupling, ( k )</td>
<td>0.875</td>
</tr>
<tr>
<td>Input ripple current</td>
<td>10% of input current (( I_{in} ))</td>
</tr>
<tr>
<td>Primary coupled inductors: ( L_{1P}, L_{2P}, L_{3P} )</td>
<td>18( \mu )H, 100kHz (( L_{1P}-45A, L_{2P}-15A, L_{3P}-15A ))</td>
</tr>
<tr>
<td>Secondary coupled inductors ( L_{1S}, L_{2S}, L_{3S} )</td>
<td>72( \mu )H, 10A, 100kHz</td>
</tr>
<tr>
<td>Power switches ( Z_1, Z_2, Z_3 ) (IGBTs)</td>
<td>IXDN55N120D1 (1200V, 100A, 2.3V)</td>
</tr>
<tr>
<td>Voltage lift diode, ( D_{lift} )</td>
<td>VS-UFB280FA40 (400V, 170A)</td>
</tr>
<tr>
<td>Diodes ( D_1, D_{MI} )</td>
<td>DSEI2X101-12A (1.2kV, 91A)</td>
</tr>
<tr>
<td>Diode ( D_{IBC} )</td>
<td>DSEI2X101-06A (600V, 96A)</td>
</tr>
<tr>
<td>Diodes ( D_{MI}, D_0 )</td>
<td>DSS2X61-01A (100V, 60A)</td>
</tr>
</tbody>
</table>
Multiplier diodes $D_{M2}-D_{M5}$

Capacitors $C_{l/f}, C_{M2}$

Multiplier capacitors $C_{M1}, C_{M5}$

Multiplier capacitor $C_{M3}$

Capacitors $C_{M4}, C_{M6}, C_0$

Heat sink

<table>
<thead>
<tr>
<th>Component</th>
<th>Part Number</th>
<th>Rating</th>
</tr>
</thead>
<tbody>
<tr>
<td>DSEI2X31-06C</td>
<td>DSEI2X31-06C</td>
<td>(600V, 30A)</td>
</tr>
<tr>
<td>BC2799-ND</td>
<td>BC2799-ND</td>
<td>(5µF/1.2kV)</td>
</tr>
<tr>
<td>495-4186-ND</td>
<td>495-4186-ND</td>
<td>(4.7µF/250V)</td>
</tr>
<tr>
<td>P14214-ND</td>
<td>P14214-ND</td>
<td>(4.7µF/450V)</td>
</tr>
<tr>
<td>338-1376-ND</td>
<td>338-1376-ND</td>
<td>(4.7µF/1.5kV)</td>
</tr>
<tr>
<td>294-1112-ND</td>
<td>294-1112-ND</td>
<td></td>
</tr>
</tbody>
</table>

Fig. 5(c) shows the experimental waveforms of the voltage across the capacitors at various key positions in the proposed converter. The waveform presented in CH1 shows the potential difference across $C_{l/f}$ while the remaining three channels (CH2, CH3 and CH4) demonstrate the voltage developed across $C_{M2}$, $C_{M4}$ and $C_{M6}$ respectively. Since $C_{l/f}$ is present between two interleaved phases, the voltage developed across $C_{l/f}$ is the voltage contributed by one IBC leg. The voltage built up across $C_{M2}$, $C_{M4}$ and $C_{M6}$ clearly validate the implemented gain extension concept. As the capacitor $C_{M6}$ is located at the far end of Stage 2 and no further gain extension is envisaged, the potential across $C_{M6}$ is same as the output voltage.

Fig. 5(d) shows the waveform of the current through the primary windings $L_{1P}$, $L_{2P}$ and $L_{3P}$ along with the input current, $I_{in}$. The total input current is shared among the three interleaved phases. As anticipated, the current distribution in the interleaved phases is unequal due to asymmetry. Since the switches are triggered with a uniform phase shift of $120^\circ$, the input current ripple is minimised. The magnitude of ripple current matches very closely with the designed value; the minor deviation (0.7 A) is attributed to the leakage present in the CIs.
(a) CH1 – CH3 (50V/div): Voltage across gate and emitter terminals ($V_{GE}$) of the power switches $Z_1$, $Z_2$ and $Z_3$ and CH4 (500V/div): Output voltage. (Time scale 2.5μs/div)

(b) CH1 (100V/div): Input voltage, CH2 and CH3 (50V/div): Gate pulses applied to switches $Z_2$ and $Z_3$, CH4 (500V/div): Output voltage. (Time scale 2.5μs/div).
(c) CH1 (500V/div): Voltage across $C_{L1P}$, CH2 (500V/div): Voltage across $C_{M2}$, CH3 (500V/div): Voltage across $C_{M4}$, CH4 (2kV/div): Voltage across $C_{M6}$. (Time scale 25µs/div)

(d) CH1 (50A/div), CH2 (10A/div), CH3 (5A/div): Current through $L_{1P}$, $L_{2P}$ and $L_{3P}$ respectively, CH4 (50A/div): Input current $I_{in}$. (Time scale 2.5µs/div)

**Fig. 5.** Experimental results showing the voltage and current waveform captured using the oscilloscope: Test carried out at full load condition.

The second test on the proposed converter is conducted to determine (i) the voltage and current stresses experienced by the semiconductor devices at full load condition and (ii) the operating efficiency of the proposed HGHP converter when load varies from 75% to 115% of...
full load. Fig. 6(a) shows the voltage stress on $Z_3$ as related to its gate pulse and the output voltage. The turn ON and turn OFF instants of $Z_3$ are in accordance with the applied gate pulse. The voltage stress on $Z_3$ is only about 12% of $V_0$. Despite of large voltage conversion ratio realised in this converter; the switch voltage stress is very low because (i) voltage gain extension occurs in Stage 2, and (ii) VMCs present in Stage 2 act as passive recycling network for transferring the stored energy in the leakage inductance to the load.

The waveforms presented in Fig. 6(b) to 6(d) pertain to efficiency computation at various load conditions. Under full load condition, the experimented converter operates at 92.63\% efficiency. This efficiency value is acceptable since the converter simultaneously offers a high voltage gain of 18.3 and delivers 3 kW output power. The voltage reduction from the rated load to 115\% of full load condition is about 50 V which translates to 4.54\% voltage regulation at 89.78\% efficiency. At 75\% load condition, the voltage regulation is 8.63\% while the efficiency is 90.10\%. Energy storage elements contribute to a reasonably good voltage regulation even when operated under open loop mode. For DC microgrid, a constant DC bus voltage is needed to ensure proper operation of various loads connected to the common DC bus. When load condition tends to fluctuate, the energy storage elements used in the proposed HGHP converter act as energy buffer and maintain the DC bus voltage at the designed (specified) value. When operating at light load condition (75\% of full load), the proposed converter yields a slightly higher voltage at the output. The output capacitor is rated to withstand this marginally higher output voltage. To maintain the DC output voltage at a constant and specified value and protect the other equipment/load connected to the common DC bus, duty ratio of the switches needs to be reduced slightly.
(a) CH1(50V/div): Gate pulse of $Z_3$, CH2(100V/div): Voltage stress on $Z_3$, CH3(1kV/div): Output voltage. (Time scale 2.5$\mu$s/div)

(b) CH1(100V/div) and CH2(50A/div): Voltage and current at the input terminals respectively, CH3(2kV/div) and CH4(2.5A/div): Voltage and current at the output, MATH(5kVA/div) (channel ‘M’): Output power at full load. (Time scale 5$\mu$s/div).
Fig. 6. Experimental results showing the voltage and current waveform captured using the oscilloscope: Test carried out at full load condition.

The loss distribution of the converter under full load condition is calculated from (24)-(26).

\[
P_{\text{switch\_loss}} = I_{\text{switch\_RMS}}^2 \times R_{\text{switch\_ON}} + P_{\text{switch\_ON}} + P_{\text{switch\_OFF}} \tag{24}
\]

\[
P_{\text{diode\_loss}} = V_{\text{diode\_ON}} \times I_{\text{diode\_Avg}} + I_{\text{diode\_RMS}}^2 \times R_{\text{diode}} \tag{25}
\]
where

\[ P_{\text{CI loss}} = I_{\text{py}}^2 \times R_{\text{py}} + I_{\text{sy}}^2 \times R_{\text{sy}} + P_{\text{iron}} \] (26)

\( P_{\text{switch loss}}, \ P_{\text{diode loss}}, \ P_{\text{CI loss}} \), and \( P_{\text{iron}} \) are the power loss occurring in the switches, diodes, coupled inductor and magnetic/ferrite core of CI respectively.

\( P_{\text{switch ON}} \) and \( P_{\text{switch OFF}} \) are respectively the turn ON and turn OFF power loss occurring in the switches.

\( I_{\text{switch}}, \ I_{\text{diode}}, \ I_{\text{py}} \) and \( I_{\text{sy}} \) are the current flowing through switch, diode, primary winding of CI and secondary winding of CI respectively.

\( R_{\text{switch}}, \ R_{\text{diode}}, \ R_{\text{py}} \) and \( R_{\text{sy}} \) are the resistance of the switch, diode, primary winding and secondary winding of CI respectively.

From the manufacturers’ datasheet, the required parameters like \( R_{\text{switch ON}}, \ R_{\text{diode}} \) and \( P_{\text{iron}} \) are obtained and the respective losses are calculated. Fig. 7 shows the loss distribution of the converter under full load condition. The conduction loss and switching loss occurring across the power switches account for about 45% of the total losses. Generally, polypropylene capacitors are efficient and contribute to very low losses. To minimise the losses occurring across the connecting wires, thick stranded conductors with low resistance is used. Thick multi-layered printed circuit board (PCB) tracks are used to reduce the losses occurring across them. Overall, the losses occurring across the capacitors, losses occurring in the PCB, connecting wires, etc. are minimal and work out to 2% of the total power.

Fig. 8 shows the top view photograph of the implementation of the proposed converter laid on the PCB. Modules with SOT227 package are used as power switches and diodes. The coupled inductors operate at the 100ckHz frequency and are wound using litz wire to reduce conduction losses, size and volume. Consequently, the three CIs are conveniently
accommodated on the PCB itself. Switches and diodes are naturally cooled using individual peel and stick type heat dissipators. Fig. 9 shows the front view photograph of the assembled converter. Capacitors $C_{m4}$, $C_{m6}$ and $C_0$ were the tallest components with a height of about 0.065 m. The overall dimensions of the converter are $0.385m \times 0.230m \times 0.065m$ (length $\times$ width $\times$ height).

Fig. 7. Loss distribution of the experimented converter operating at rated condition.
**Fig. 8.** Photograph showing the top view of the implemented HGHP DC-DC converter for DC Microgrids.

**Fig. 9** Front view photograph of the proposed HGHP converter.
4 Performance Analysis and Comparison with Few Existing Converters

The performance of the presented HGHP DC-DC converter suitable for DC microgrid applications is evaluated considering variations in turns ratio ($n$), the duty ratio ($D$), the coefficient of coupling ($k$) of CIs and load conditions, simulation results are presented below.

4.1 Efficiency and Output Voltage

Fig. 7(a) shows the output voltage and efficiency values at various load conditions obtained during simulation and experimentation for the HGHP DC-DC converter suitable for DC microgrid applications. The peak operating efficiency of the converter is about 92% under full load condition. When the load varies from 75% to 115% of rated load, the practical efficiency fluctuates within a narrow 3% band. This narrow fluctuation is an advantage, and due to the presence of energy storage elements which ensure appropriate delivery of demanded output power over the load range considered. The output voltage remains almost constant over a load variation ranging from 75% to 115% of full load and proves the voltage gain capability of the converter while validating the design hypothesis.

Fig. 10(b) shows the plot of ideal voltage gain ($k = 1$) versus duty ratio variation for the adopted and few existing converters. Proposed HGHP DC-DC converter offers the highest voltage gain compared to other converters. Converter presented in [47] and [55] offer the same gain as turns ratio is unity for this converter. Fig10(c) shows the voltage gain variation of the proposed converter with variation in turns ratio $n$. The desired operating point is achieved at $n = 2$ and $k = 0.875$ (experimentally determined value). Since CIs are used in the proposed converter, its voltage gain varies as the coupling coefficient varies. This variation is shown in Fig. 10(d). The change in voltage gain at a particular duty ratio when $k$ varies from 0.875 to 1 is very less and proves that the variation in $k$ does not drastically affect the practical output voltage.
4.2. Voltage Gain and Power Handling Capability

To appreciate the advantageous features of the proposed HGHP DC-DC converter, its main attributes are benchmarked with converters presented in [52], [53], [55] and [56]. Table 2 provides some important attributes which are compared. All the converters that are compared provide a voltage gain of more than ten except the converter in [53], whose voltage gain is 9.83. Converters presented in [52], [53] and [55] use two CIs with a relatively smaller turns ratio of 1 and 1.6 in [52]. Though the voltage gain of converters is higher than 10 (except [53]), their power handling capability is limited to 1 kW mainly due to the gain extension technique adopted. In the proposed converter, the presence of IBC as its first stage with three CIs enables the converter to handle 3 kW power at the desired voltage level.

(a)
(b)

Ideal Gain
M=20

(c)

Operating Point (k=0.875)
D=0.55, n=2.0, M=18.3
Fig. 10. Plots representative of the main performance indicators of the proposed converter

(a) Efficiency and output voltage of the proposed converter under simulation and experimentation.

(b) Voltage gain plot of the proposed converter and some existing converters when \( k = 1 \).

(c) Voltage gain variation of the developed converter for various values of \( n \).

(d) Voltage gain variation of the developed converter for various values of \( k \).

4.1.1 Switch Stress

In the proposed converter, the voltage stress experienced by \( Z_1 \) and \( Z_2 \) is 36% while \( Z_3 \) experiences a very low voltage stress of only about 12% of the output voltage. This reduced switch voltage stress is attributed to Stage 2 where the majority of gain extension takes place. Switches used in [52] and [55] experience a stress of about half of their output voltage while
in [53], the switching stress is about one-fourth of the output. In [56], switches are subjected to the least voltage stress of 12.5% of its output voltage due to clamping technique adopted.

4.1.2 Component Count

Proposed converter has maximum components and converter in [52] uses the least number of components. The presence of more components in the presented converter is acceptable since higher voltage gain, and power transfer of 3kW is simultaneously achieved. In [56], additional switches are used to reduce the voltage stress on the main switches resulting in increased component count. Other converters presented in Table 2 have a moderate component count.
Table 2. Comparison of proposed HGHP DC-DC converter with some converters proposed in the scientific literature [52]-[56].

<table>
<thead>
<tr>
<th>Attributes</th>
<th>Converters presented in</th>
<th>Proposed</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input voltage ( (V_{in}) )</td>
<td>24 60 36 15 60</td>
<td>60</td>
</tr>
<tr>
<td>Output voltage ( (V_0) )</td>
<td>380 590 400 200 1100</td>
<td></td>
</tr>
<tr>
<td>Voltage gain ( (M) )</td>
<td>15.83 9.83 11.11 13.33 18.33</td>
<td></td>
</tr>
<tr>
<td>Output power ( (kW) )</td>
<td>0.5 0.87 1 0.4 3</td>
<td></td>
</tr>
<tr>
<td>Duty ratio ( (D) )</td>
<td>0.56 0.615 0.67 0.65 0.55</td>
<td></td>
</tr>
<tr>
<td>Magnetic components used</td>
<td>2 CI 2CI 2 CI 3CI 3 CI</td>
<td></td>
</tr>
<tr>
<td>CI turns ratio ( (n) )</td>
<td>1.6 1 1 2 2</td>
<td></td>
</tr>
<tr>
<td>Generalised voltage gain expression with coupling coefficient ( k = 1 )</td>
<td>( \frac{4n + 1}{1 - D} ) ( \frac{3n + 1}{1 - D} ) ( \frac{4}{1 - D} ) ( \frac{4n}{1 - D} ) ( \frac{3(1 + nk)}{1 - D} )</td>
<td></td>
</tr>
<tr>
<td>Gain extension technique</td>
<td>CI, diode stages</td>
<td>Interleaved, three winding CI and VMC</td>
</tr>
<tr>
<td>Expression for maximum voltage stress on power switch</td>
<td>( \frac{V_0}{4n + 1} ) ( \frac{V_{C_r}}{n} ) ( \frac{V_0}{2} ) ( \frac{V_0}{4n} ) ( \frac{V_0}{1 + nk} )</td>
<td></td>
</tr>
<tr>
<td>Switch stress (% of ( V_0 ))</td>
<td>51.35 24.4 50 12.5 36.36</td>
<td></td>
</tr>
<tr>
<td>No. of switches</td>
<td>2 2 4 6 3</td>
<td></td>
</tr>
<tr>
<td>No. of diodes</td>
<td>4 8 0 4 10</td>
<td></td>
</tr>
<tr>
<td>No. of capacitors</td>
<td>5 5 4 7 8</td>
<td></td>
</tr>
<tr>
<td>Total component count</td>
<td>13 16 14 20 23</td>
<td></td>
</tr>
</tbody>
</table>
4.3 MPPT Implementation

The proposed HGHP DC-DC converter is designed to be used in DC microgrid applications, one of the main applications is interfacing PV systems. Consequently, the converter should be able to perform additional functionalities as Maximum Power Point Tracking (MPPT). To facilitate easy implementation of a MPPT algorithm, the relation between the duty ratio \( D \), equivalent resistance (seen by the source) at maximum power point \( R_{\text{Conv-MPP}} \) and load resistance \( R_L \) is provided in (27).

\[
D = 1 - (3 + 3n) \sqrt{ \frac{R_{\text{Conv-MPP}}}{R_L} } 
\]  

(27)

5 Challenges

Although DC microgrid has bright opportunities and is the right candidate to encounter the future energy demand by integrating DG and the loads, some challenges are associated while implementing a DC distribution scheme [58]. Some of the main challenges are discussed below.

(i) The use of high DC bus voltages of the order of 1 kV is more attractive at distribution levels as they reduce the current and copper weight. However, when DC bus voltage exceeds 75 V, additional safety measures are required to avoid electrocution [59] – [62]. Apart from proper electrical insulation, an active protection system is also required to detect insulation failures, leakage currents, etc., and to isolate the power supply and loads. Though designing a complete safety system for DC is difficult, other safety mechanisms like residual current detector (RCD) and insulation resistance monitoring device (IMD) guarantee the necessary safety and monitoring functions.
(ii) The growth of DC distribution is constrained due to lack of higher current interrupting capacity of DC circuit breaker (CB), protection schemes and operational experience. However, expert research on fault detection and protection of DC distribution system has resulted in advanced protection schemes which are capable of investigating different faults and prove to be effective for DC distribution system with distributed energy sources [63] – [66].

(iii) When DC distribution is carried out through underground (UG) cables in urban areas, corrosion is likely to be more compared to AC [67].

(iv) Though there are different arguments towards the voltage levels and standards, to reach a breakthrough, standardisation of voltage levels is an important step. Organisations like Emerge Alliance (EA), the European Telecommunications Standards Institute (ETSI), the International Electrotechnical Commission (IEC) and IEEE are actively involved in evolving and fixing the appropriate policies and standards.

(v) Manufacturing of DC compatible appliances is still in a nascent stage. Industries which manufacture products for DC distribution systems are very few since the demand for DC compatible loads/appliances is very low. On the other hand, minor modifications can be done in the present appliances or devices to make them “DC-ready” [68] – [70].

6 Prospects

Despite some stiff challenges, DC microgrids and DC distribution, in particular, have wider implications on efficient energy utilisation. The motivation to encounter the challenges may be obtained by looking at some of the bright prospects that DC distribution is expected to offer. Some of the ways to easily shift/adapt towards DC distribution are as follows:
(i) Present AC distribution lines can be upgraded into DC with few minor infrastructure changes resulting in increased power transfer capacity [71].

(ii) In residential and commercial buildings, it is standard practice to install multiple wiring networks for lighting loads, ring mains, the internet, intercom, etc., Therefore, adding a supplementary DC electrical network is perfectly achievable [72]. Further, DC sockets can be provided at modest cost. Introducing DC lines in residences will increase the market demand for DC appliances. Resultantly, they will keep getting better, and a wider range of products that work in DC will come into existence. In the long run, this phenomenon is expected to make DC appliances more affordable and efficient.

(iii) In longer time perspective, smaller communities may find that their off-grid DC microgrid systems more reliable and satisfy their needs [73]. The quality of the power delivered to the customer will be improved. Further, as the distance between the generating station and load centre comes down drastically, the utility bills will also be reduced.

Therefore, DC distribution has (i) a prosperous future, (ii) the potential to efficiently and effectively replace the existing AC system and (iii) provide reliable and high-quality power at a much affordable cost.

7 Conclusion

A high gain high power DC-DC converter suitable for DC microgrid, considering integration of PV system is developed. A non-isolated DC-DC converter has been developed to simultaneously realise high voltage gain at a higher power level for DC microgrid applications. When the converter is supplied from a 60 V input, the converter yielded 1.1 kV at the output terminals and delivered 3 kW of power at 92.6% efficiency. Many key
performance attributes of the proposed converter has been compared with some existing converters in order to highlight the versatility of the presented converter. When fed from a RES, the benefits of DC distribution systems, key challenges involved in adapting to DC and prospects have been thoroughly discussed. Further, the efficiency at which DC distribution systems and DC microgrids supply modern loads combined with the ease of integrating DG and storage elements makes the overall concept appealing. As an extension, a DC microgrid setup can be made to operate in a smarter way viz; avoiding brownouts and or blackouts, taking care of critical loads and other load demands depending upon the source availability by incorporating intelligence and internet connectivity. Standardisation of voltage levels, safety, protection and other key issues like DC compatible appliance manufacturing, creating awareness among the consumers, installation, operation and availability of qualified and trained technicians with experience in DC distribution systems should be addressed.

8 Acknowledgement

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